

Electronic Acknowledgement Receipt

EFS ID:	1074105
Application Number:	10812015
Confirmation Number:	2799
Title of Invention:	Gallium nitride (GaN)-based semiconductor light emitting diode and method for manufacturing the same
First Named Inventor:	Seung Wan Chae
Correspondence Address:	LOWE HAUPTMAN GILMAN & BERNER, LLP - Suite 310 1700 Diagonal Road Alexandria VA 22314 US 7036841111 -
Filer:	Benjamin J. Hauptman/Ayesha Wilson
Filer Authorized By:	Benjamin J. Hauptman
Attorney Docket Number:	2336-255
Receipt Date:	09-JUN-2006
Filing Date:	30-MAR-2004
Time Stamp:	17:25:53
Application Type:	Utility
International Application Number:	

Payment information:

Submitted with Payment	no
------------------------	----

File Listing:

Document Number	Document Description	File Name	File Size(Bytes)	Multi Part	Pages
1	Amendment - After Non-Final Rejection	20060609Amendment.pdf	327891	no	8

Warnings:

Information:

Total Files Size (in bytes):	327891
-------------------------------------	--------

This Acknowledgement Receipt evidences receipt on the noted date by the USPTO of the indicated documents, characterized by the applicant, and including page counts, where applicable. It serves as evidence of receipt similar to a Post Card, as described in MPEP 503.

New Applications Under 35 U.S.C. 111

If a new application is being filed and the application includes the necessary components for a filing date (see 37 CFR 1.53(b)-(d) and MPEP 506), a Filing Receipt (37 CFR 1.54) will be issued in due course and the date shown on this Acknowledgement Receipt will establish the filing date of the application.

National Stage of an International Application under 35 U.S.C. 371

If a timely submission to enter the national stage of an international application is compliant with the conditions of 35 U.S.C. 371 and other applicable requirements a Form PCT/DO/EO/903 indicating acceptance of the application as a national stage submission under 35 U.S.C. 371 will be issued in addition to the Filing Receipt, in due course.